

IN THE CLAIMS

A listing of the claims presented in this patent application appears below. This listing replaces all prior versions and listing of claims in this patent application.

- [1] (Original) A two-beam semiconductor laser device comprising:
- a two-beam semiconductor element having a first and a second semiconductor laser elements that can be driven independently and that are formed integrally on a substrate; and
 - a submount having, mounted on a front part thereof, the two-beam semiconductor laser element with a light-emitting face thereof directed forward and having a first and a second electrode pads connected to electrodes of the first and second semiconductor laser element by being kept in contact therewith,
- wherein the first and second electrode pads are formed to extend farther behind the two-beam semiconductor laser element, and are wire-bonded behind the two-beam semiconductor laser element.
- [2] (Original) The two-beam semiconductor laser device of claim 1,
- wherein the first and second electrode pads are wire-bonded at a rear end of the submount.
- [3] (Currently Amended) The two-beam semiconductor laser device of claim 1 ~~or 2~~,
- wherein a distance from the rear end of the two-beam semiconductor laser element to a position where the first and second electrode pads are wire-bonded is 300 μm or shorter.
- [4] (Currently Amended) The two-beam semiconductor laser device of ~~one of claims~~ claim 1 to 3,
- wherein a lateral length of the submount is 400 μm or more but 700 μm or less.

- [5] (Currently Amended) The two-beam semiconductor laser device of ~~one of claims~~
claim 1 to 4,
wherein the submount is mounted in a package composed of a frame and a
resin member.
- [6] (Original) The two-beam semiconductor laser device of claim 5,
wherein the two-beam semiconductor laser device is built as a three-
terminal two-beam semiconductor laser device having three terminals.